MAX6509xAUK Rev. A

RELIABILITY REPORT

FOR

MAX6509xAUK

PLASTIC ENCAPSULATED DEVICES

February 12, 2002

MAXIM INTEGRATED PRODUCTS

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Conclusion

The MAX6509 successfully meets the quality and reliability standards required of all Maxim products. In addition, Maxim's continuous reliability monitoring program ensures that all outgoing product will continue to meet Maxim's quality and reliability standards.

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I. Device Description

A. General

The MAX6509 is a fully integrated, resistor-programmable temperature switch with thresholds set by an external resistor. It requires only one external resistor to set the temperature threshold within a wide -40°C to +125°C temperature range. The MAX6509 provides an open-drain output.

The switch operate with a +2.7V to +5.5V single supply while providing a temperature threshold accuracy of $\pm 0.5^{\circ}$ C (typ) or $\pm 4.7^{\circ}$ C (max) and typically consume 32µA supply current. Hysteresis is pin selectable to 2°C or 10°C.

The MAX6509 is available in 5-pin SOT23 packages.

B. Absolute Maximum Ratings

| <u>ltem</u> | Rating |
|---|-----------------------|
| | |
| Vcc to GND | -0.3V to +6V |
| /OUT to GND | -0.3V to +6V |
| SET, HYST, OUTSET | -0.3V to (VCC + 0.3V) |
| Output Current (all pins) | 20mA |
| Input Current (all pins) | 20mA |
| Storage Temp. | -65°C to +150°C |
| Lead Temp. (10 sec.) | +300°C |
| Junction Temperature | +150°C |
| Continuous Power Dissipation (TA = +70°C) | |
| 5-Pin SOT23 | 571mW |
| Derates above +70°C | |
| 5-Pin SOT23 | 7.1mW/°C |

II. Manufacturing Information

| A. Description: | Resistor-programmable SOT Temperature Switch |
|----------------------------------|--|
| B. Process: | S12 (Standard 1.2 micron silicon gate CMOS) |
| C. Number of Device Transistors: | 234 |
| D. Fabrication Location: | Oregon or California, USA |
| E. Assembly Location: | Malaysia or Thailand |
| F. Date of Initial Production: | January, 2000 |

III. Packaging Information

| Α. | Package Type: | 5-Lead SOT23 |
|----|--|---------------------------|
| В. | Lead Frame: | Copper |
| C. | Lead Finish: | Solder Plate |
| D. | Die Attach: | Silver-filled Epoxy |
| E. | Bondwire: | Gold (1.0 mil dia.) |
| F. | Mold Material: | Epoxy with silica filler |
| G. | Assembly Diagram: | Buildsheet # 05-1601-0075 |
| H. | Flammability Rating: | Class UL94-V0 |
| I. | Classification of Moisture Sensitivity per JEDEC standard JESD22-A112: | Level 1 |

IV. Die Information

| A. Dimensions: | 52 x 35 mils |
|----------------------------|--|
| B. Passivation: | Si_3N_4/SiO_2 (Silicon nitride/ Silicon dioxide) |
| C. Interconnect: | Aluminum/Si (Si = 1%) |
| D. Backside Metallization: | None |
| E. Minimum Metal Width: | 1.2 microns (as drawn) |
| F. Minimum Metal Spacing: | 1.2 microns (as drawn) |
| G. Bondpad Dimensions: | 5 mil. Sq. |
| H. Isolation Dielectric: | SiO ₂ |
| I. Die Separation Method: | Wafer Saw |

V. Quality Assurance Information

| Α. | Quality Assurance Contacts: | Jim Pedicord (Reliability Lab Manager) |
|----|-----------------------------|---|
| | | Bryan Preeshl (Executive Director of QA) |
| | | Kenneth Huening (Vice President) |
| _ | | |
| В. | Outgoing Inspection Level: | 0.1% for all electrical parameters guaranteed by the Datasheet. |

- 0.1% For all Visual Defects.
- C. Observed Outgoing Defect Rate: < 50 ppm
- D. Sampling Plan: Mil-Std-105D

VI. Reliability Evaluation

A. Accelerated Life Test

The results of the 135°C biased (static) life test are shown in **Table 1**. Using these results, the Failure Rate (λ) is calculated as follows:

 $\lambda = 1 = 1.83 \quad \text{(Chi square value for MTTF upper limit)} \\ 192 \times 4389 \times 80 \times 2 \\ \text{Temperature Acceleration factor assuming an activation energy of 0.8eV} \\ \lambda = 13.57 \times 10^{-9} \qquad \lambda = 13.57 \text{ F.I.T. (60\% confidence level @ 25°C)}$

This low failure rate represents data collected from Maxim's reliability qualification and monitor programs. Maxim also performs weekly Burn-In on samples from production to assure reliability of its processes. The reliability required for lots which receive a burn-in qualification is 59 F.I.T. at a 60% confidence level, which equates to 3 failures in an 80 piece sample. Maxim performs failure analysis on rejects from lots exceeding this level. The attached Burn-In Schematic (Spec. # 06-5527) shows the static circuit used for this test. Maxim also performs 1000 hour life test monitors quarterly for each process. This data is published in the Product Reliability Report (**RR-1M**).

B. Moisture Resistance Tests

Maxim evaluates pressure pot stress from every assembly process during qualification of each new design. Pressure Pot testing must pass a 20% LTPD for acceptance. Additionally, industry standard 85°C/85%RH or HAST tests are performed quarterly per device/package family.

C. E.S.D. and Latch-Up Testing

The MS30 die type has been found to have all pins able to withstand a transient pulse of ± 1000 V, per Mil-Std-883 Method 3015 (reference attached ESD Test Circuit). Latch-Up testing has shown that this device withstands a current of ± 250 mA and/or ± 20 V.

Table 1Reliability Evaluation Test Results

| MAX | 650 | 9xU | AK |
|-----|-----|-----|----|
| | | | |

| TEST ITEM | TEST CONDITION | FAILURE IDENTIFICATION | SAMPLE SIZE | NUMBER OF FAILURES |
|----------------------------|---|----------------------------------|----------------|-----------------------|
| Static Life Test | : (Note 1) | | | |
| | Ta = 135°C Biased Time = 192 hrs. | DC Parameters & functionality | 80 | 0 |
| Moisture Testir | ng (Note 2) | | | |
| Pressure Pot | Ta = 121°C P = 15 psi. RH= 100% Time = 168hrs. | DC Parameters & functionality | 355 | 0 |
| 85/85 | Ta = 85°C RH = 85% Biased Time = 1000hrs. | DC Parameters & functionality | 77 | 0 |
| Mechanical Stress (Note 2) | | | | |
| Temperature Cycle | -65°C/150°C 1000 Cycles Method 1010 | DC Parameters | 77 | 0 |

Note 1: Life Test Data may represent plastic D.I.P. qualification lots for the Small Outline package.

Note 2: Generic Package/Process data

Attachment #1

| | Terminal A (Each pin individually connected to terminal A with the other floating) | Terminal B (The common combination of all like-named pins connected to terminal B) |
|----|---|---|
| 1. | All pins except V _{PS1} <u>3/</u> | All V _{PS1} pins |
| 2. | All input and output pins | All other input-output pins |

TABLE II. Pin combination to be tested. 1/2/

1/ Table II is restated in narrative form in 3.4 below.

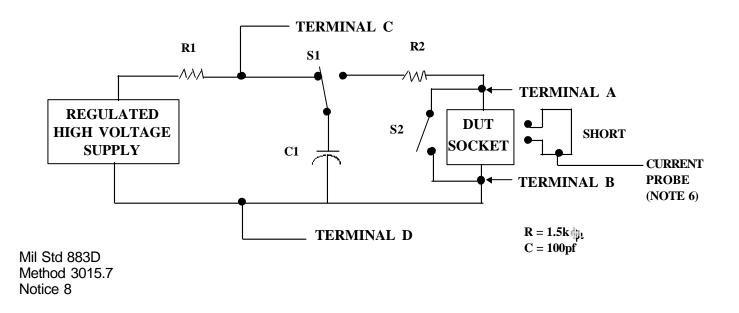
2/ No connects are not to be tested.

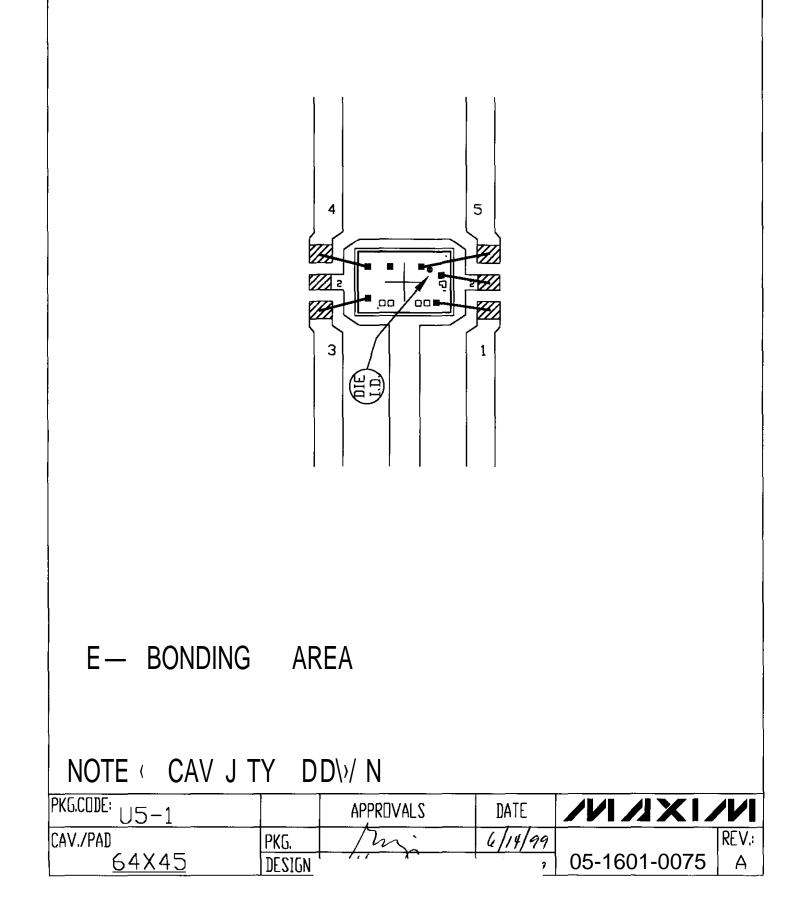
<u>3/</u>Repeat pin combination I for each named Power supply and for ground

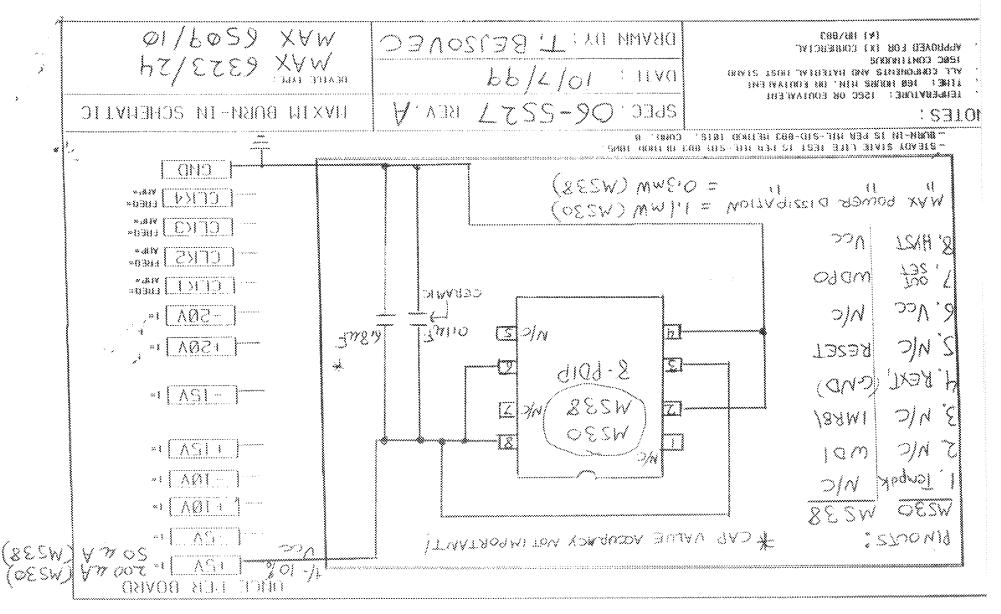
(e.g., where V_{PS1} is V_{DD} , V_{CC} , V_{SS} , V_{BB} , GND, $+V_S$, $-V_S$, V_{REF} , etc).

3.4 Pin combinations to be tested.

- a. Each pin individually connected to terminal A with respect to the device ground pin(s) connected to terminal B. All pins except the one being tested and the ground pin(s) shall be open.
- b. Each pin individually connected to terminal A with respect to each different set of a combination of all named power supply pins (e.g., V_{SS1}, or V_{SS2} or V_{SS3} or V_{CC1}, or V_{CC2}) connected to terminal B. All pins except the one being tested and the power supply pin or set of pins shall be open.
- c. Each input and each output individually connected to terminal A with respect to a combination of all the other input and output pins connected to terminal B. All pins except the input or output pin being tested and the combination of all the other input and output pins shall be open.







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